



Attorney Docket No.	LIGHT2700
First Named Inventor:	Frederik Marcel Van Der Vliet
Application Number	10/644,395
Filing Date:	August 19, 2003
Examiner Name:	Wood, Kevin S.
Group/Art Unit:	2874
Title	MULTIPLEXER HAVING IMPROVED EFFICIENCY

BOX FEE AMENDMENT

Assistant Commissioner for Patents

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INFORMATION DISCLOSURE STATEMENT

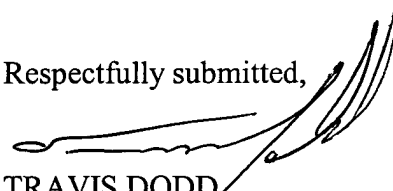
Applicant hereby cites the documents listed in the accompanying Form PTO-1449 with respect to the above reference patent application under the provision of 37 CFR 1.97(b). Copies of the documents are attached.

Because the above Patent Application was filed after June 2003, copies of the U.S. Patent Applications and the U.S. Patent Application Publications were not provided. However, the Applicant will be happy to provide these copies at the request of the Examiner.

The Examiner is respectfully requested to make the listed documents of record in connection with the prosecution of the subject application.

Date: 1-10-06

Respectfully submitted,


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SHEET	1	OF	3	Docket Number	LIGHT2700

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (If known)			
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Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ⁵ (If known)				
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